NSN 5961-01-131-5785

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-131-5785 **Inclosure Material:** Glass **Mounting Facility Quantity: Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 breakdown voltage, collector to emitter, sustained and 15.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 30.00 milliamperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 250.0 watts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** -65.0 degrees celsius case and 175.0 degrees celsius case **Special Features:** Uhf/microwave pnp bjt **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No